

1-Line Ultra Small Bi-directional TVS Diode

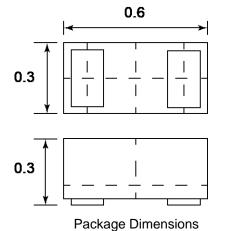
Description

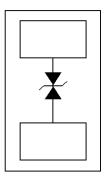
PESDU3311P0A is a bi-directional TVS (Transient Voltage Suppressor). It has been specifically designed to protect sensitive electronic components which are connected to low speed data lines and control lines from over-stress caused by ESD (Electrostatic Discharge) and Lightning . PESDU3311P0A may be used to provide ESD protection up to \pm 30KV (air and contact discharge) according to IEC61000-4-2, and withstand peak pulse current up to 9A(8/20µs) according to IEC61000-4-5 PESDU3311P0A is available in DFN0603-2 package. Standard products are Pb-free and Halogen-free.

Features

- Operating voltage: 3.3V
- Low clamping voltage
- 2-pin leadless package
- Complies with following standards:
 - -IEC 61000-4-2 (ESD) immunity test
 - Air discharge: ±30kV
 - Contact discharge: ±30kV
 - —IEC61000-4-5 (Lightning) 9A (8/20µs)
- RoHS Compliant

Dimensions and Pin Configuration





Circuit and Pin Schematic

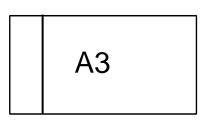
Mechanical Characteristics

- Package: DFN0603-2 (0.6×0.3×0.3mm)
- Case Material: "Green" Molding Compound.
- Moisture Sensitivity: Level 1 per J-STD-020
- Marking Information: See Below

Applications

- Cellular Handsets
- USB V_{BUS} and CC Line Protection
- Microphone Line Protection
- GPIO Protection

Marking Information



A3 = Device Marking Code

Ordering Information

Part Number	Shipping	Reel Size
PESDU3311P0A	10000/Tape & Reel	7 inch



Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit	
Peak Pulse Power (8/20µs)	Ррк 90		W	
Peak Pulse Current (8/20µs)	Ірр	Ірр 9		
ESD per IEC 61000-4-2 (Air)	V	±30		
ESD per IEC 61000-4-2 (Contact)	Vesd	±30	kV	
Lead temperature	ΤL	260	Ĉ	
Operating Temperature Range	Тор	-40 ~ +85	Ĉ	
Storage Temperature Range	Тѕтс	−55 ~ +150	Ĉ	

Electrical Characteristics (TA=25°C unless otherwise specified)

Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	Vrwm			3.3	V	
Breakdown Voltage	V _{BR}	3.5	4.5	5.5	V	l⊤ = 1mA
Reverse Leakage Current	I _R			0.3	μA	V _{RWM} =3.3V
Clamping voltage 1)	V _{CL}		9.0		V	$I_{PP} = 16A, t_p = 100ns$
Dynamic resistance 1)	R _{DYN}		0.2		Ω	
Clamping voltage 2)	V _{CL}		9.0		V	V _{ESD} = 8kV
Clamping voltage 3)	Vc		4.4	6	V	I _{PP} = 1A(8/20µs pulse)
Clamping voltage 3)	Vc		7.2	10	V	I _{PP} = 9A(8/20µs pulse)
Junction Capacitance	CJ		17	22	pF	$V_R = 0V, f = 1MHz$

Notes:

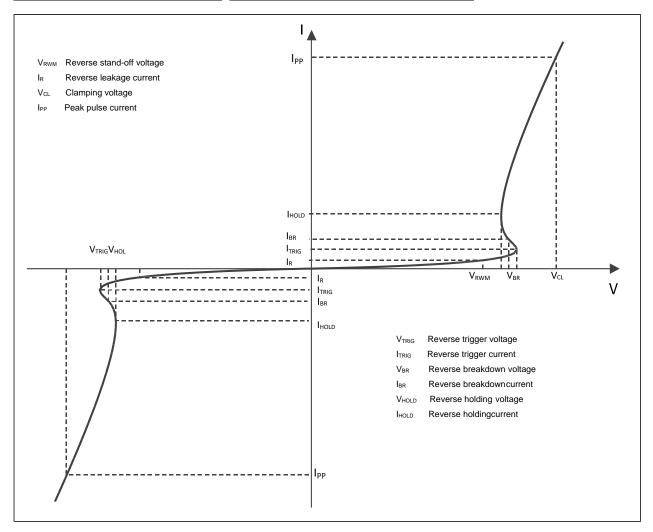
1) TLP parameter: $Z_0 = 50\Omega$, tp = 100 ns, tr = 2 ns, averaging window from 60 ns to 80 ns. RDYN is calculated from 4A to 16A.

2) Contact discharge mode, according to IEC61000-4-2.

3) Non-repetitive current pulse, according to IEC61000-4-5.



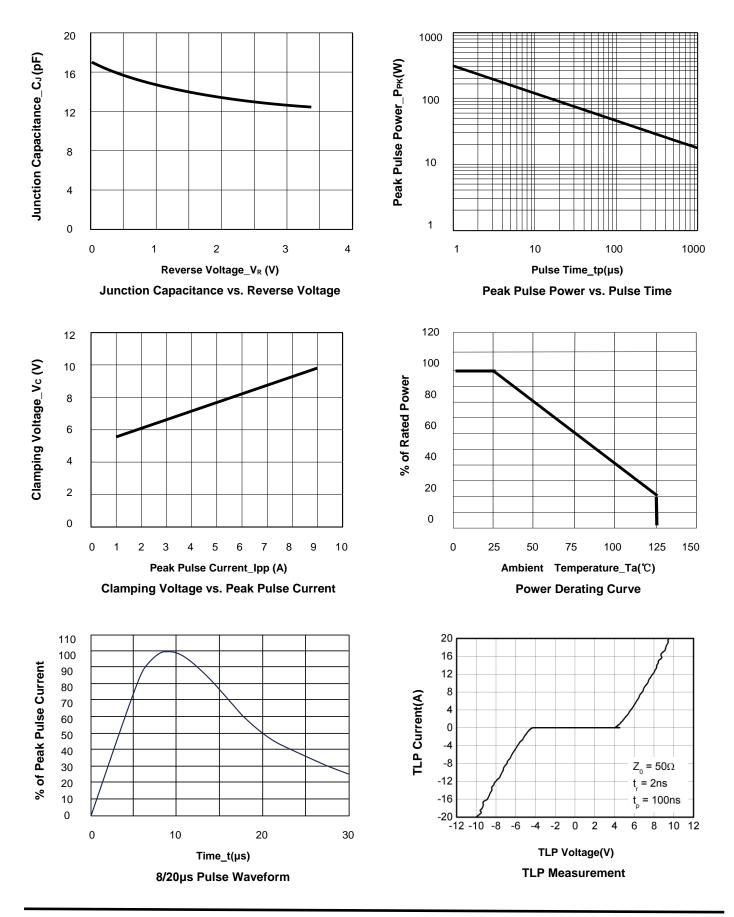
Electrical characteristics (T_A = 25°C, unless otherwise noted)



Definitions of electrical characteristics



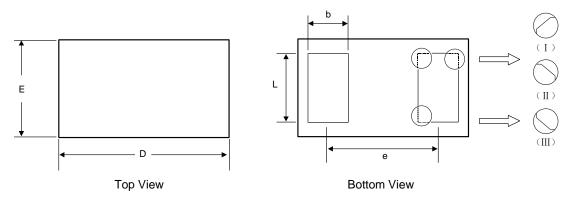
Typical Performance Characteristics (TA=25°C unless otherwise Specified)

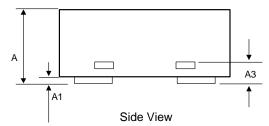






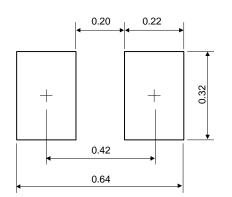
DFN0603-2 Package Outline Drawing





	Dir	Dimensions in Millimeters			
Symbol	Min.	Тур.	Max.		
А	0.230	0.300	0.350		
A1	0.000	-	0.050		
A3		0.102REF.			
D	0.550	0.600	0.670		
E	0.250	0.300	0.370		
b	0.160	0.190	0.230		
L	0.215	0.245	0.275		
е		0.360 BSC			

Recommended PCB Layout (Unit: mm)



Notes:

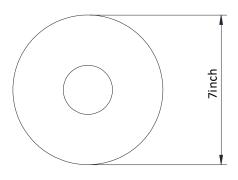
This recommended land pattern is for reference purposes only. Please consult your manufacturing group to ensure your PCB design guidelines are met.



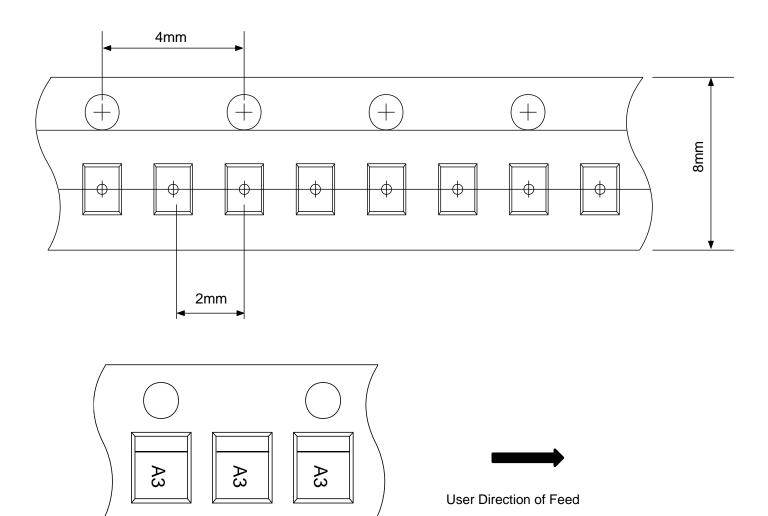


TAPE AND REEL INFORMATION

Reel Dimensions



Tape Dimensions





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